## NSN 5961-00-484-2995

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Inclosure Material:
Metal
Overall Length:
0.240 inches
Terminal Length:
1.500 inches
Overall Diameter:
0.335 inches
Internal Configuration:
Junction contact
Mounting Method:
Terminal
Terminal Circle Diameter:
0.200 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
25.0 reverse voltage, peak
Current Rating Per Characteristic:
15.00 amperes source cutoff current absolute and 1.60 amperes forward current, average of standard range
Power Rating Per Characteristic:
0.1 milliwatts small-signal input power, common-collector outside diameter
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius ambient air
Special Features:
Junction pattern arrangement: npn
Terminal Type And Quantity:
3 uninsulated wire lead
Specification Data:
80131-release5356 professional/industrial association specification
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0